



REVISION HISTORY

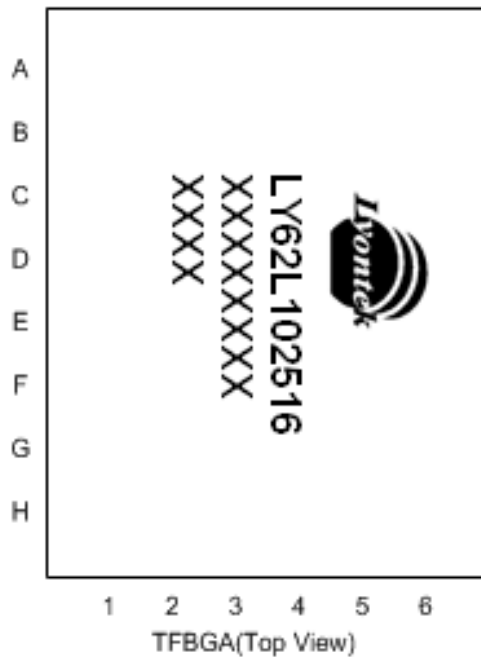
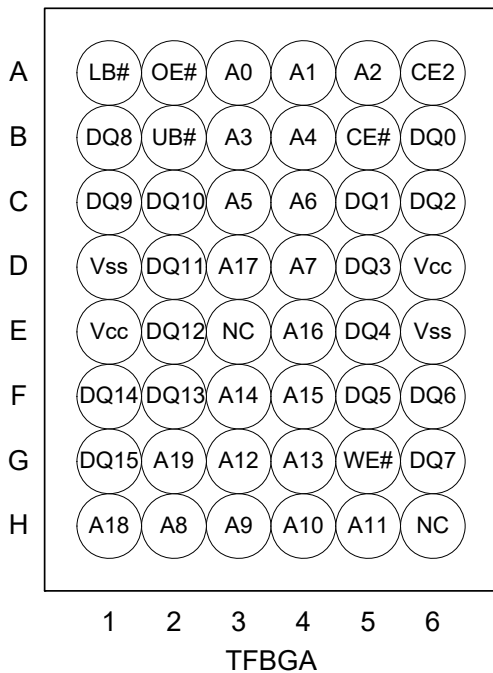
<u>Revision</u>	<u>Description</u>	<u>Issue Date</u>
Rev. 0.1	Initial Issue	Feb.20.2008
Rev. 0.2	Added SL Spec.	Jul.2.2008
Rev. 0.3	Added I _{SB1} /I _{DR} values when T _A = 25°C and T _A = 40°C Revised FEATURES & ORDERING INFORMATION Lead free and green package available to Green package available Added packing type in ORDERING INFORMATION Deleted T _{SOLDER} in ABSOLUTE MAXIMUM RATINGS	Mar.30.2009
Rev. 0.4	Revised PACKAGE OUTLINE DIMENSION in page 10	May.7.2010
Rev. 1.0	Revised Notes item 1 and 2 in page 3 1. V _{IH} (max) = V _{CC} + 2.0V for pulse width less than 6ns. 2. V _{IL} (min) = V _{SS} - 2.0V for pulse width less than 6ns.	Aug.29.2013
Rev. 1.1	Revised ORDERING INFORMATION Deleted WRITE CYCLE Notes : 1.WE#,CE#, LB#, UB# must be high or CE2 must be low during all address transitions. In page 8.	May.18.2016
Rev. 2.0	1. Deleted FEATURES Standby current : 4μA (TYP.) SL-version--Page 1 2. Deleted PRODUCT FAMILY Standby(ISB1,TYP.) :4μA(SL)--- Page 1 3. Deleted DC ELECTRICAL CHARACTERISTICS : Standby Power Supply Current : ISB1--- Page4 4. Deleted DC ELECTRICAL CHARACTERISTICS : Notes: 5--- Page 4 5. Deleted DATA RETENTION CHARACTERISTICS : Data Retention Current: IDR --- Page 9 6. Revised ORDERING INFORMATION in Page 12~Page13	Jun.18.2024



PIN CONFIGURATION



TSOP-I





ABSOLUTE MAXIMUM RATINGS*

PARAMETER	SYMBOL	RATING	UNIT
Voltage on Vcc relative to Vss	V _{T1}	-0.5 to 4.6	V
Voltage on any other pin relative to Vss	V _{T2}	-0.5 to V _{CC} +0.5	V
Operating Temperature	T _A	0 to 70(C grade)	°C
		-20 to 80(E grade)	
		-40 to 85(I grade)	
Storage Temperature	T _{STG}	-65 to 150	°C
Power Dissipation	P _D	1	W
DC Output Current	I _{OUT}	50	mA

*Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to the absolute maximum rating conditions for extended period may affect device reliability.

TRUTH TABLE

MODE	CE#	CE2	OE#	WE#	LB#	UB#	I/O OPERATION		SUPPLY CURRENT
							DQ0-DQ7	DQ8-DQ15	
Standby	H	X	X	X	X	X	High – Z	High – Z	I _{SB} , I _{SB1}
	X	L	X	X	X	X	High – Z	High – Z	
	X	X	X	X	H	H	High – Z	High – Z	
Output Disable	L	H	H	H	L	X	High – Z	High – Z	I _{CC} , I _{CC1}
	L	H	H	H	X	L	High – Z	High – Z	
Read	L	H	L	H	L	H	D _{OUT}	High – Z	I _{CC} , I _{CC1}
	L	H	L	H	H	L	High – Z	D _{OUT}	
	L	H	L	H	L	L	D _{OUT}	D _{OUT}	
Write	L	H	X	L	L	H	D _{IN}	High – Z	I _{CC} , I _{CC1}
	L	H	X	L	H	L	High – Z	D _{IN}	
	L	H	X	L	L	L	D _{IN}	D _{IN}	

Note: H = V_{IH}, L = V_{IL}, X = Don't care.



DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP. ^{*4}	MAX.	UNIT	
Supply Voltage	V _{CC}		2.7	3.0	3.6	V	
Input High Voltage	V _{IH} ^{*1}		2.2	-	V _{CC} +0.3	V	
Input Low Voltage	V _{IL} ^{*2}		-0.2	-	0.6	V	
Input Leakage Current	I _{LI}	V _{CC} ≥ V _{IN} ≥ V _{SS}	-1	-	1	μA	
Output Leakage Current	I _{LO}	V _{CC} ≥ V _{OUT} ≥ V _{SS} , Output Disabled	-1	-	1	μA	
Output High Voltage	V _{OH}	I _{OH} = -1mA	2.2	2.7	-	V	
Output Low Voltage	V _{OL}	I _{OL} = 2mA	-	-	0.4	V	
Average Operating Power supply Current	I _{CC}	Cycle time = Min. CE# = V _{IL} and CE2 = V _{IH} I _{I/O} = 0mA Other pins at V _{IL} or V _{IH}	-55	-	45	60	mA
			-70	-	30	45	mA
	I _{CC1}	Cycle time = 1μs CE# ≤ 0.2V and CE2 ≥ V _{CC} -0.2V I _{I/O} = 0mA other pins at 0.2V or V _{CC} -0.2V	-	8	16	mA	
Standby Power Supply Current	I _{SB}	CE# = V _{IH} or CE2 = V _{IL} Other pins at V _{IL} or V _{IH}	-	0.3	2	mA	
	I _{SB1}	CE# ≥ V _{CC} -0.2V or CE2 ≤ 0.2V Other pins at 0.2V or V _{CC} -0.2V	LL	-	10	60	μA
			LLE	-	10	80	μA
			LLI	-	10	100	μA

Notes:

- V_{IH}(max) = V_{CC} + 2.0V for pulse width less than 6ns.
- V_{IL}(min) = V_{SS} - 2.0V for pulse width less than 6ns.
- Over/Undershoot specifications are characterized, not 100% tested.
- Typical values are included for reference only and are not guaranteed or tested.
Typical values are measured at V_{CC} = V_{CC}(TYP.) and T_A = 25°C

**CAPACITANCE (TA = 25°C, f = 1.0MHz)**

PARAMETER	SYMBOL	MIN.	MAX	UNIT
Input Capacitance	C _{IN}	-	6	pF
Input/Output Capacitance	C _{I/O}	-	8	pF

Note : These parameters are guaranteed by device characterization, but not production tested.

AC TEST CONDITIONS

Input Pulse Levels	0.2V to V _{CC} - 0.2V
Input Rise and Fall Times	3ns
Input and Output Timing Reference Levels	1.5V
Output Load	C _L = 30pF + 1TTL, I _{OH} /I _{OL} = -1mA/2mA

AC ELECTRICAL CHARACTERISTICS**(1) READ CYCLE**

PARAMETER	SYM.	LY62L102516-55		LY62L102516-70		UNIT
		MIN.	MAX.	MIN.	MAX.	
Read Cycle Time	t _{RC}	55	-	70	-	ns
Address Access Time	t _{AA}	-	55	-	70	ns
Chip Enable Access Time	t _{ACE}	-	55	-	70	ns
Output Enable Access Time	t _{OE}	-	30	-	35	ns
Chip Enable to Output in Low-Z	t _{CLZ} *	10	-	10	-	ns
Output Enable to Output in Low-Z	t _{OLZ} *	5	-	5	-	ns
Chip Disable to Output in High-Z	t _{CHZ} *	-	20	-	25	ns
Output Disable to Output in High-Z	t _{OHZ} *	-	20	-	25	ns
Output Hold from Address Change	t _{OH}	10	-	10	-	ns
LB#, UB# Access Time	t _{BA}	-	55	-	70	ns
LB#, UB# to High-Z Output	t _{BHZ} *	-	25	-	30	ns
LB#, UB# to Low-Z Output	t _{BLZ} *	10	-	10	-	ns

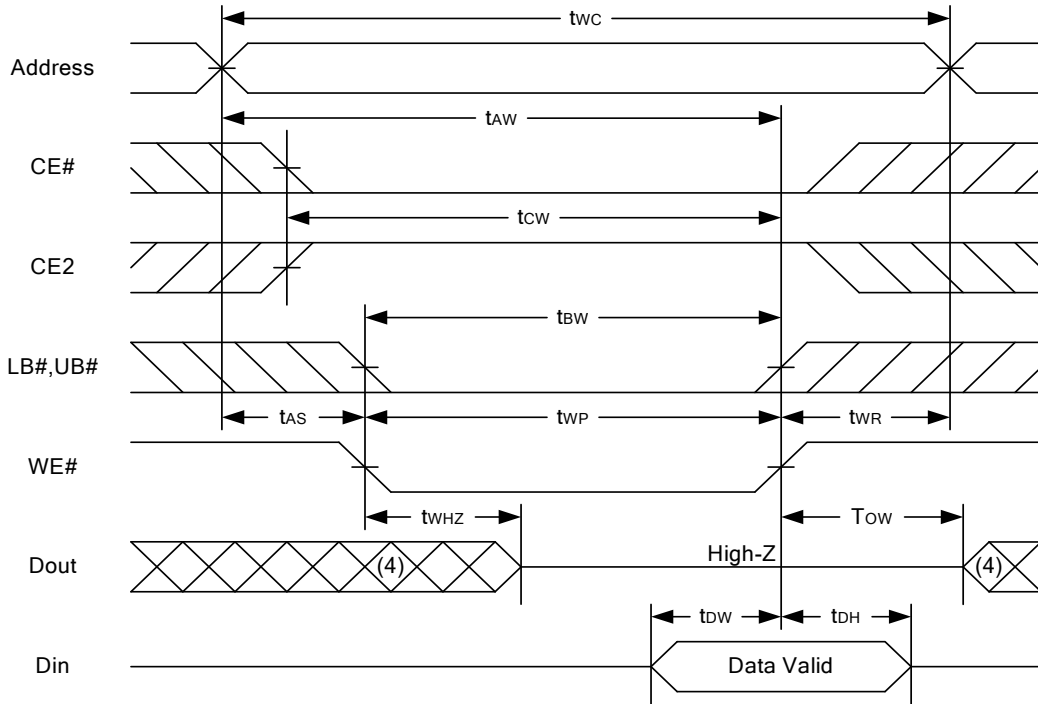
(2) WRITE CYCLE

PARAMETER	SYM.	LY62L102516-55		LY62L102516-70		UNIT
		MIN.	MAX.	MIN.	MAX.	
Write Cycle Time	t _{WC}	55	-	70	-	ns
Address Valid to End of Write	t _{AW}	50	-	60	-	ns
Chip Enable to End of Write	t _{CW}	50	-	60	-	ns
Address Set-up Time	t _{AS}	0	-	0	-	ns
Write Pulse Width	t _{WP}	45	-	55	-	ns
Write Recovery Time	t _{WR}	0	-	0	-	ns
Data to Write Time Overlap	t _{DW}	25	-	30	-	ns
Data Hold from End of Write Time	t _{DH}	0	-	0	-	ns
Output Active from End of Write	t _{OW} *	5	-	5	-	ns
Write to Output in High-Z	t _{WHZ} *	-	20	-	25	ns
LB#, UB# Valid to End of Write	t _{BW}	45	-	60	-	ns

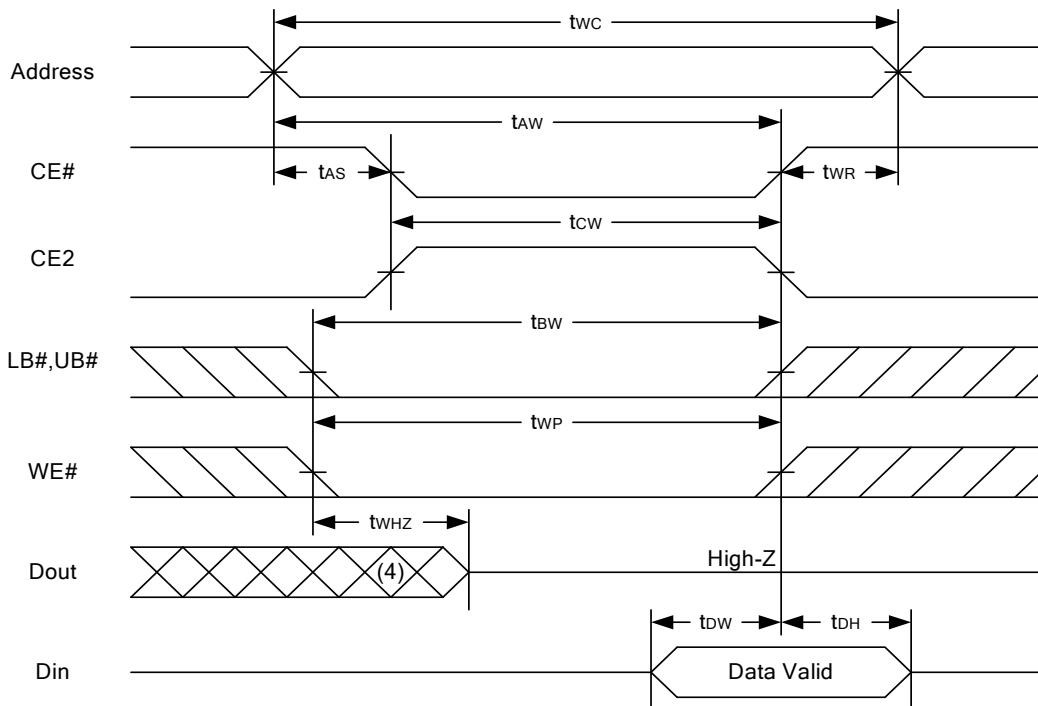
*These parameters are guaranteed by device characterization, but not production tested.



WRITE CYCLE 1 (WE# Controlled) (1,2,4,5)

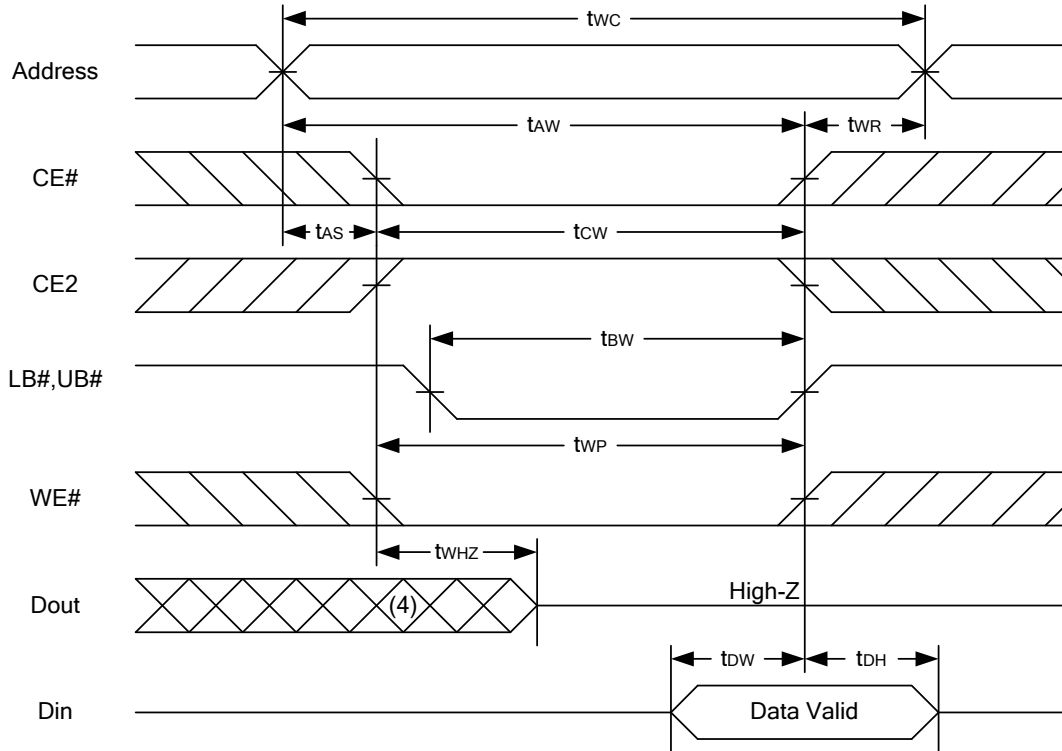


WRITE CYCLE 2 (CE# and CE2 Controlled) (1,4,5)





WRITE CYCLE 3 (LB#,UB# Controlled) (1,4,5)



Notes :

1. A write occurs during the overlap of a low CE#, high CE2, low WE#, LB# or UB# = low.
2. During a WE# controlled write cycle with OE# low, t_{WP} must be greater than $t_{WHZ} + t_{DW}$ to allow the drivers to turn off and data to be placed on the bus.
3. During this period, I/O pins are in the output state, and input signals must not be applied.
4. If the CE#, LB#, UB# low transition and CE2 high transition occurs simultaneously with or after WE# low transition, the outputs remain in a high impedance state.
5. t_{OW} and t_{WHZ} are specified with $C_L = 5pF$. Transition is measured $\pm 500mV$ from steady state.



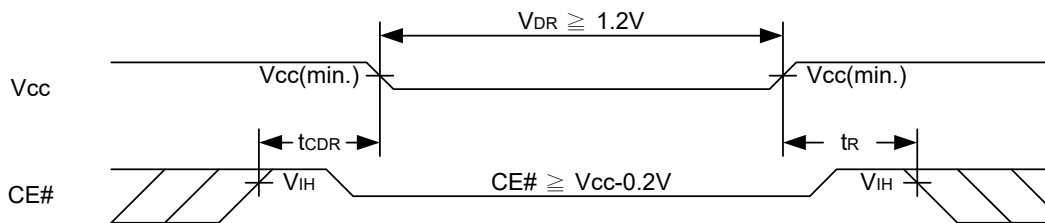
DATA RETENTION CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
Vcc for Data Retention	V _{DR}	CE# ≥ V _{CC} - 0.2V or CE2 ≤ 0.2V	1.2	-	3.6	V	
Data Retention Current	I _{DR}	V _{CC} = 1.2V CE# ≥ V _{CC} -0.2V or CE2 ≤ 0.2V other pins at 0.2V or V _{CC} -0.2V	LL	-	4	50	μA
			LLE	-	4	60	μA
			LLI	-	4	80	μA
Chip Disable to Data Retention Time	t _{CDR}	See Data Retention Waveforms (below)	0	-	-	ns	
Recovery Time	t _R		t _{RC} *	-	-	ns	

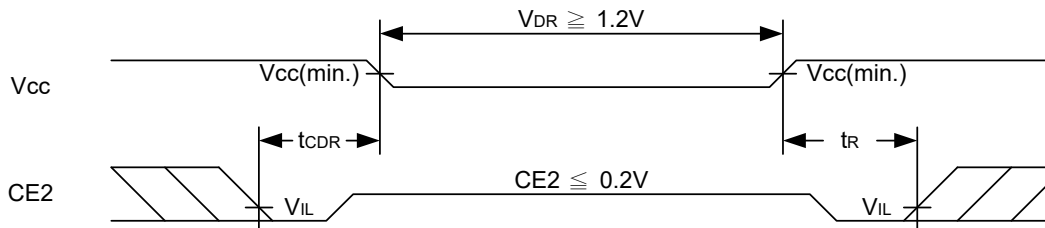
t_{RC}* = Read Cycle Time

DATA RETENTION WAVEFORM

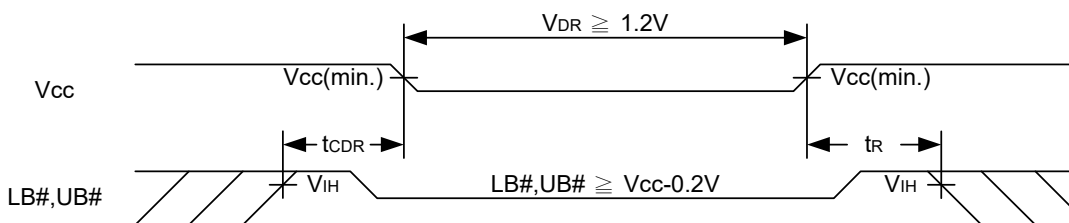
Low Vcc Data Retention Waveform (1) (CE# controlled)



Low Vcc Data Retention Waveform (2) (CE2 controlled)

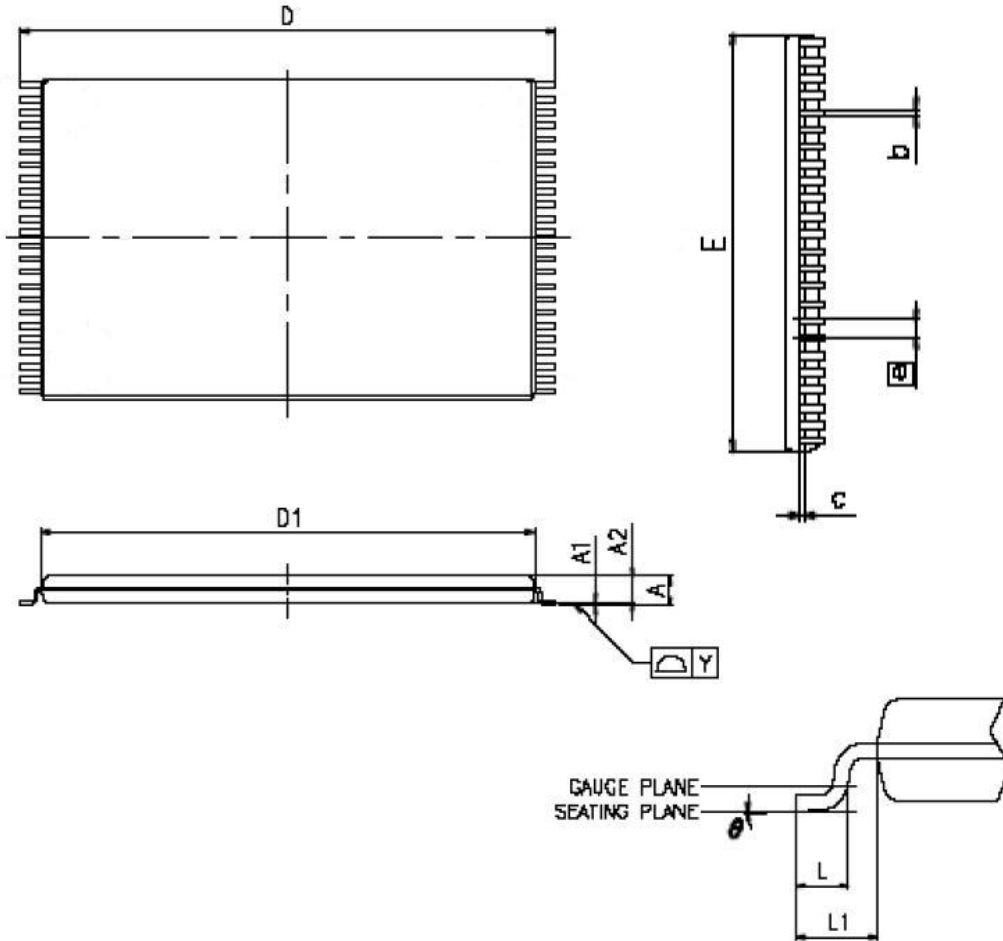


Low Vcc Data Retention Waveform (3) (LB#, UB# controlled)



PACKAGE OUTLINE DIMENSION

48-pin 12mm x 20mm TSOP-I Package Outline Dimension



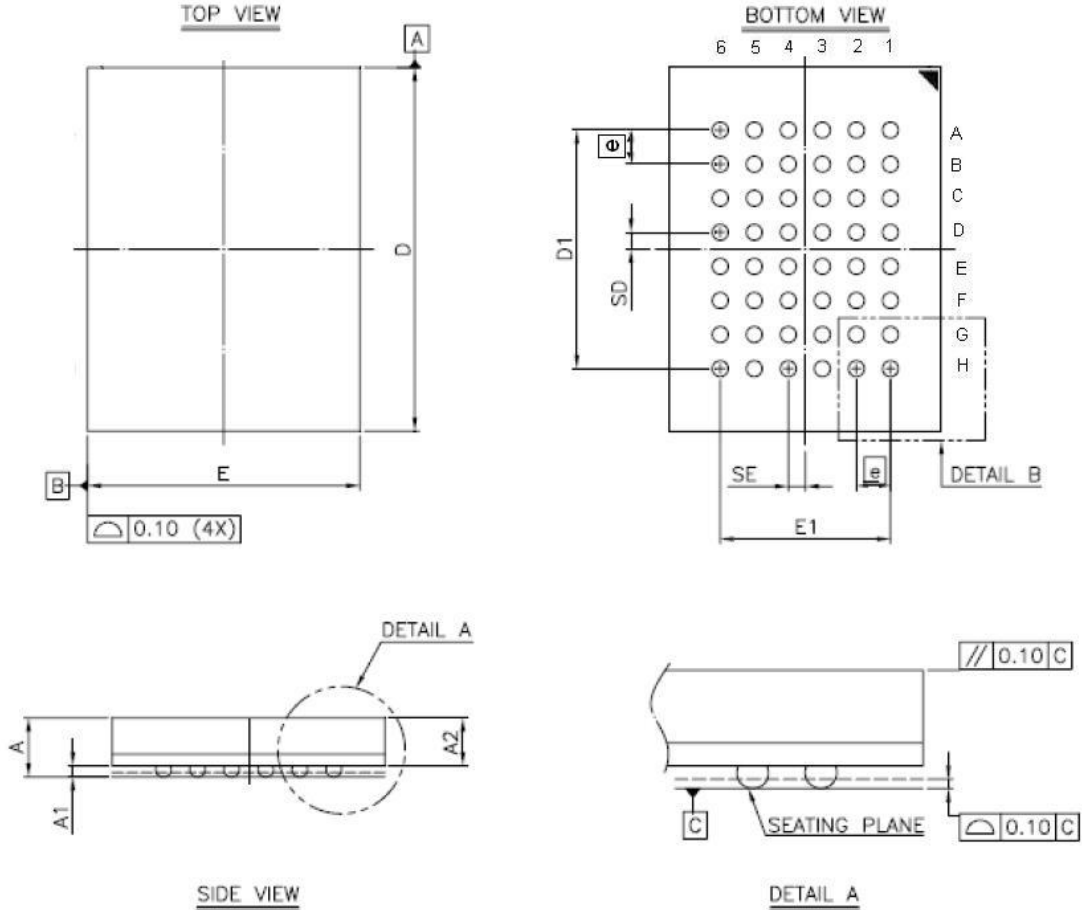
VARIATIONS (ALL DIMENSIONS SHOWN IN MM)

SYMBOLS	MIN.	NOM.	MAX
A	-	-	1.20
A1	0.05	-	0.15
A2	0.95	1.00	1.05
b	0.17	0.22	0.27
c	0.10	-	0.21
Δ D	19.80	20.00	20.20
Δ D1	18.30	18.40	18.50
Δ E	11.90	12.00	12.10
\square	0.50 BASIC		
L	0.50	0.60	0.70
Δ L1	-	0.80	-
Δ Y	-	-	0.10
Δ θ	0°	-	5°

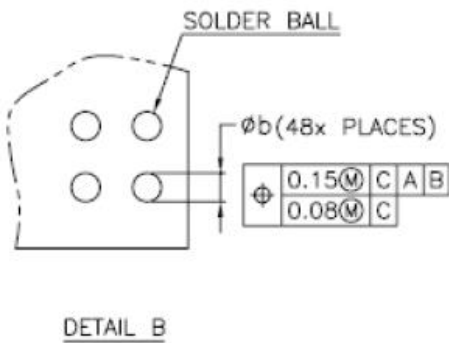
NOTES:

1. JEDEC OUTLINE : MO-142 DD
2. PROFILE TOLERANCE ZONES FOR D1 AND E DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE MOLD PROTRUSION ON E IS 0.15mm PER SIDE AND ON D1 IS 0.25mm PER SIDE.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08mm TOTAL IN EXCESS OF THE b DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT.

48-ball 6mm × 8mm TFBGA Package Outline Dimension



SYM.	DIMENSION (mm)			DIMENSION (inch)		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	—	—	1.40	—	—	0.055
A1	0.20	0.25	0.30	0.008	0.010	0.012
A2	—	—	1.05	—	—	0.041
b	0.30	0.35	0.40	0.012	0.014	0.016
D	7.95	8.00	8.05	0.313	0.315	0.317
D1	5.25 BSC			0.207 BSC		
E	5.95	6.00	6.05	0.234	0.236	0.238
E1	3.75 BSC			0.148 BSC		
SE	0.375 TYP			0.015 TYP		
SD	0.375 TYP			0.015 TYP		
⊕	0.75 BSC			0.030 BSC		



NOTE:
 1. CONTROLLING DIMENSION : MILLIMETER.
 2. REFERENCE DOCUMENT : JEDEC MO-207.

ORDERING INFORMATION
[Production Status: M/P]

Package Type	Access Time (Speed)(ns)	Power Type	Temperature Range(°C)	Packing Type	Lyontek Item No.
48-Pin 12mmx20mm TSOP-I	55	Ultra Low Power	0°C~70°C	Tray	LY62L102516LL-55LL
				Tape Reel	LY62L102516LL-55LLT
			-20°C~80°C	Tray	LY62L102516LL-55LLE
				Tape Reel	LY62L102516LL-55LLET
			-40°C~85°C	Tray	LY62L102516LL-55LLI
				Tape Reel	LY62L102516LL-55LLIT
	70	Ultra Low Power	0°C~70°C	Tray	LY62L102516LL-70LL
				Tape Reel	LY62L102516LL-70LLT
			-20°C~80°C	Tray	LY62L102516LL-70LLE
				Tape Reel	LY62L102516LL-70LLET
			-40°C~85°C	Tray	LY62L102516LL-70LLI
				Tape Reel	LY62L102516LL-70LLIT

ORDERING INFORMATION
[Production Status: EOL]

Power Type : Special Ultra Low Power

Package Type	Access Time (Speed)(ns)	Temperature Range(°C)	Packing Type	EOL Item No.	Substitute Product
48-ball 6mmx8mm TFBGA	55	0°C~70°C	Tray	LY62L102516GL-55SL	LY62L102516BGL-45SL
			Tape Reel	LY62L102516GL-55SLT	LY62L102516BGL-45SLT
		-20°C~80°C	Tray	LY62L102516GL-55SLE	LY62L102516BGL-45SLI
			Tape Reel	LY62L102516GL-55SLET	LY62L102516BGL-45SLIT
		-40°C~85°C	Tray	LY62L102516GL-55SLI	LY62L102516BGL-45SLI
			Tape Reel	LY62L102516GL-55SLIT	LY62L102516BGL-45SLIT
	70	0°C~70°C	Tray	LY62L102516GL-70SL	LY62L102516BGL-45SL
			Tape Reel	LY62L102516GL-70SLT	LY62L102516BGL-45SLT
		-20°C~80°C	Tray	LY62L102516GL-70SLE	LY62L102516BGL-45SLI
			Tape Reel	LY62L102516GL-70SLET	LY62L102516BGL-45SLIT
		-40°C~85°C	Tray	LY62L102516GL-70SLI	LY62L102516BGL-45SLI
			Tape Reel	LY62L102516GL-70SLIT	LY62L102516BGL-45SLIT



Lyontek Inc.

LY62L102516

Rev. 2.0

1024K X 16 BIT LOW POWER CMOS SRAM

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